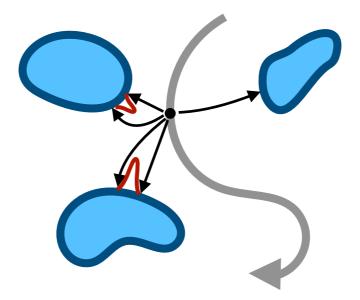
Ramo Shockley theory



Philipp Windischhofer

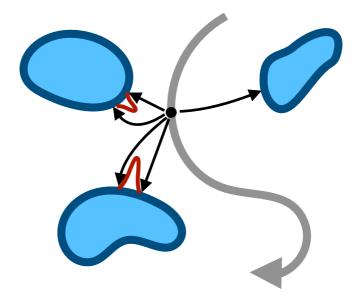
University of Chicago

UK Advanced Instrumentation Training; May 14, 2024



1

How to compute the electrical signal induced in your detector



Philipp Windischhofer

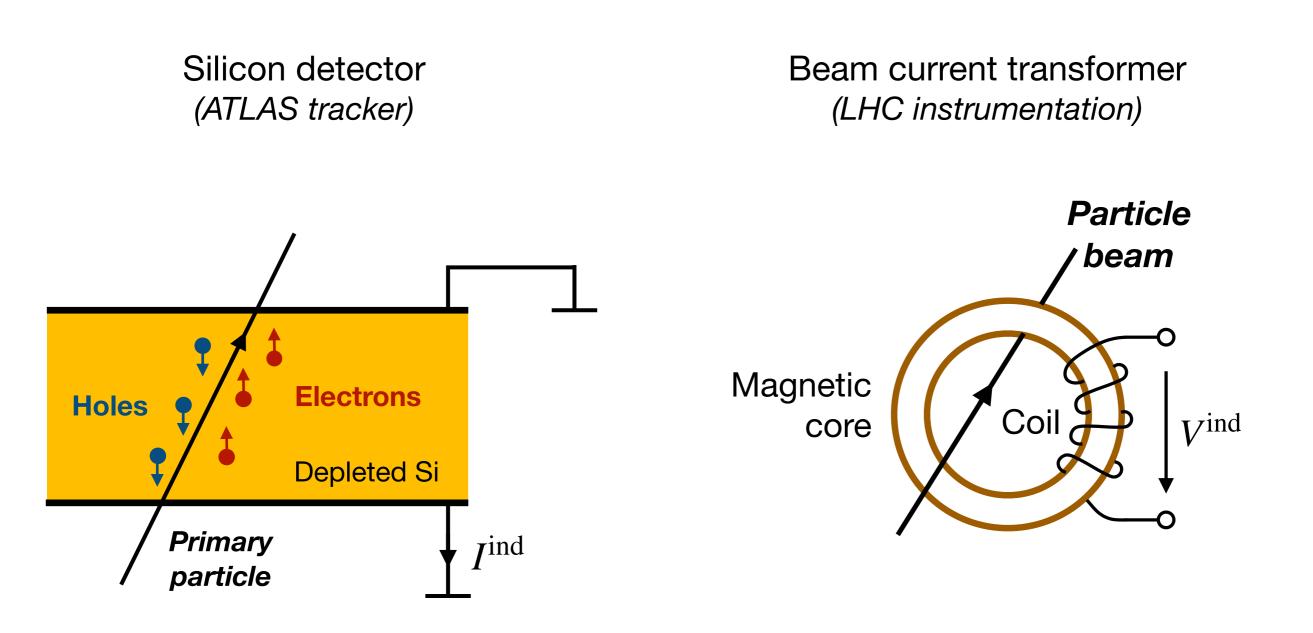
University of Chicago

UK Advanced Instrumentation Training; May 14, 2024



From moving charges to electrical signals

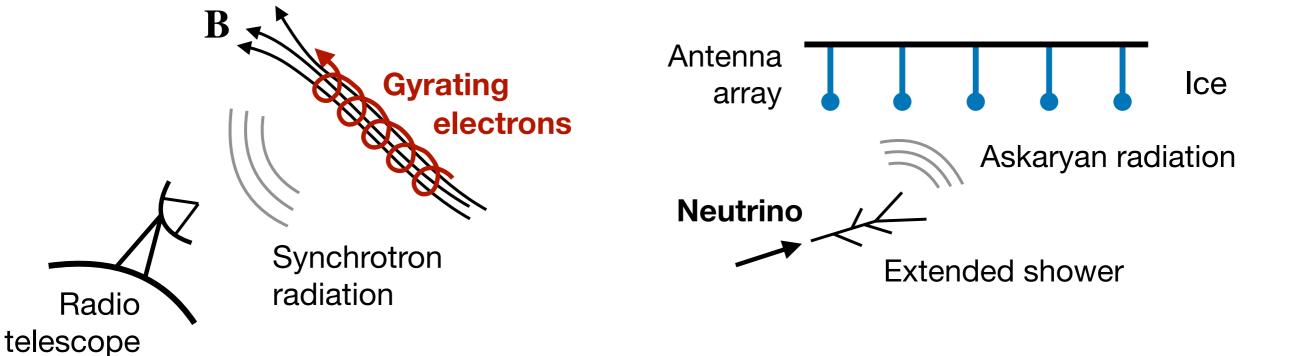
Many types of **particle detectors** generate **electrical signals** when **exposed to moving charged particles**



From moving charges to electrical signals

Many types of **particle detectors** generate **electrical signals** when **exposed to moving charged particles**

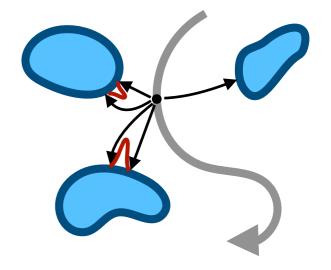
Radio astronomy *(e.g. ALMA)* Neutrino observatories (e.g. RNO-g)

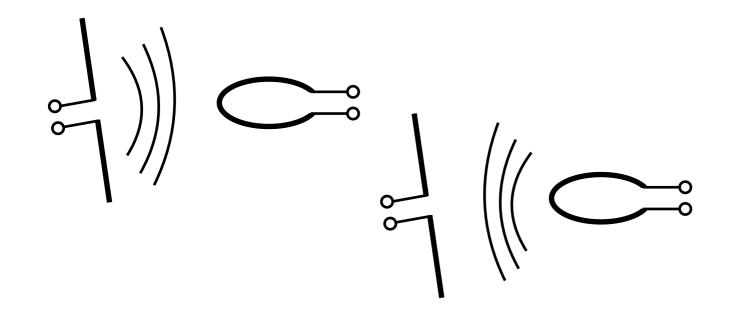


Goals for today

The physics / intuition behind signal formation

Electrostatics, surface charges, induction, ...



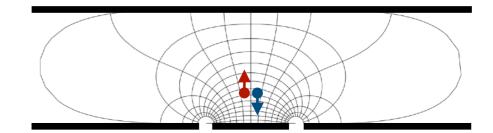


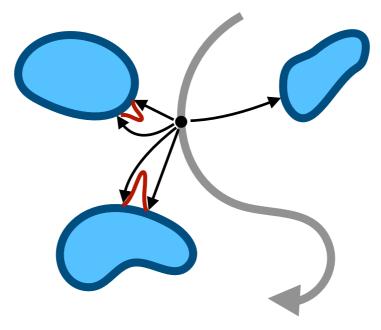
A general and efficient method

Without approximations — they just muddle the water

Signals in silicon detectors

Pixels, LGADs, ...



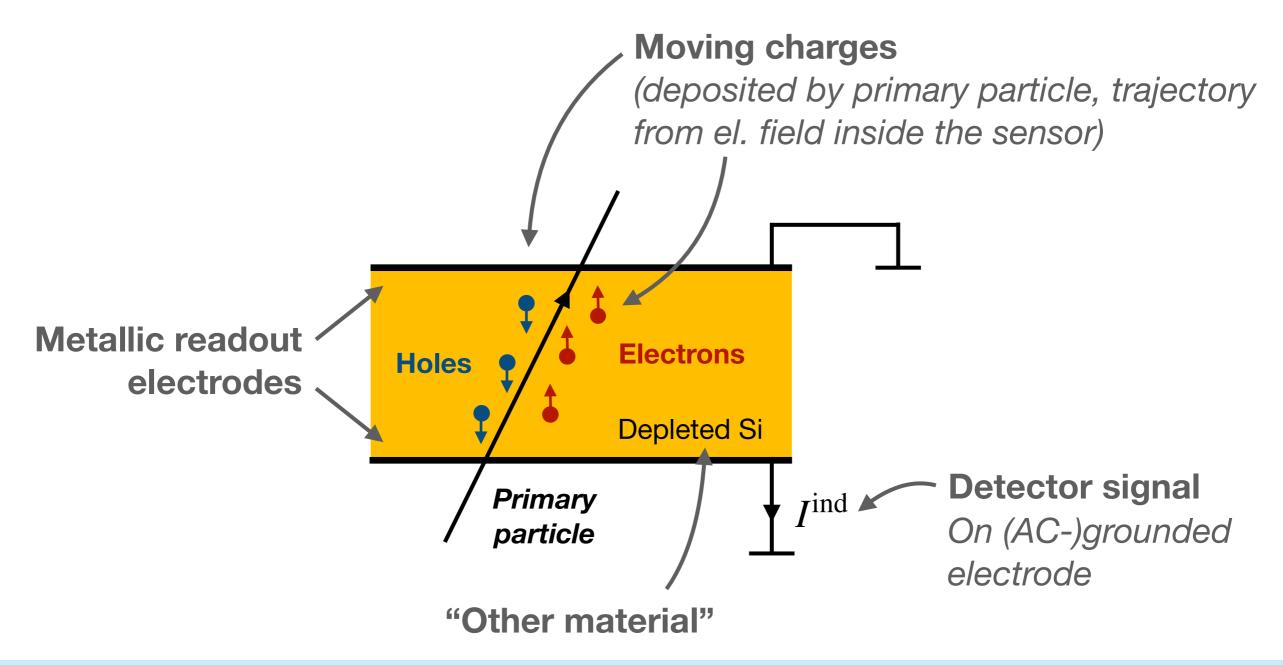


The physics of signal formation

Moving charges and conducting electrodes

For today:

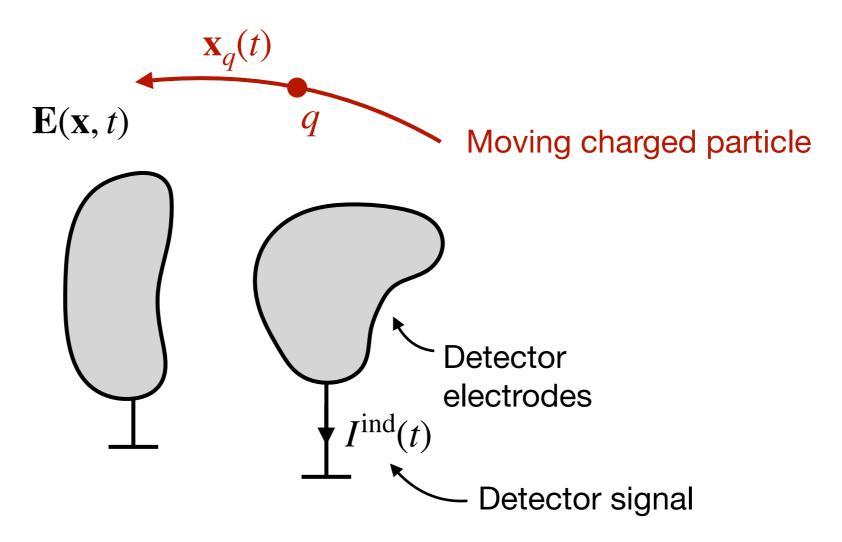
Detector = arrangement of **metallic electrodes** (and other materials) through which a **charged particle moves** along a **known trajectory**



Moving charges and conducting electrodes

For today:

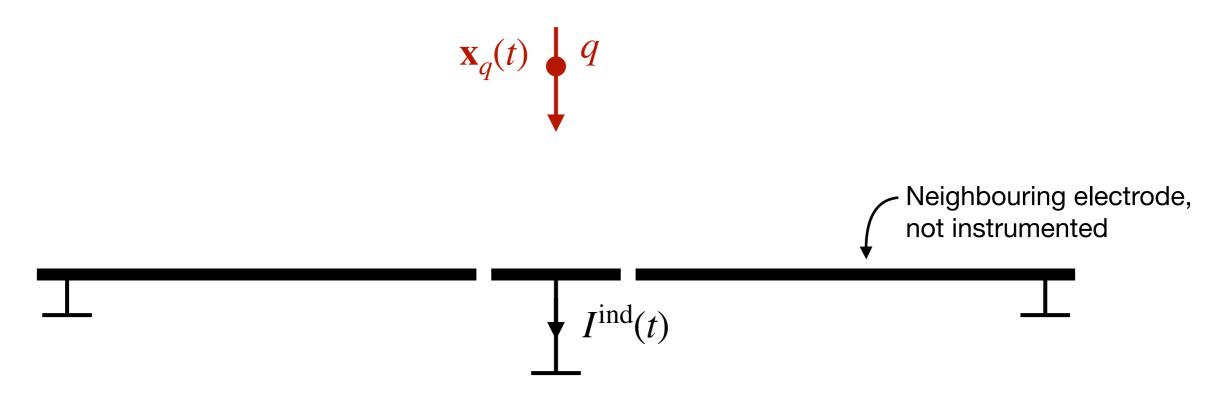
Detector = arrangement of **metallic electrodes** (and other materials) through which a **charged particle moves** along a **known trajectory**



Charged particle in front of a grounded strip electrode

(Later: signal on electrodes that are **not** grounded)

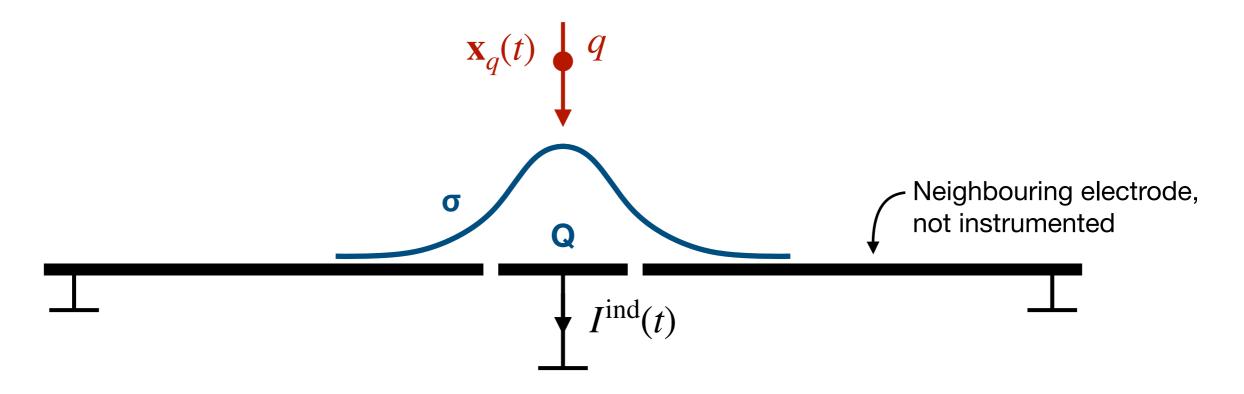
- **1.) Charge creates electric field** (assume charge moves slowly → electrostatics)
- **2.)** Electrode builds surface charge density σ (need to satisfy E = 0 in a conductor)
 - 3.) Total charge Q on strip electrode: integral over surface charge density
 - 4.) Total current from electrode: negative change in time of total charge



Charged particle in front of a grounded strip electrode

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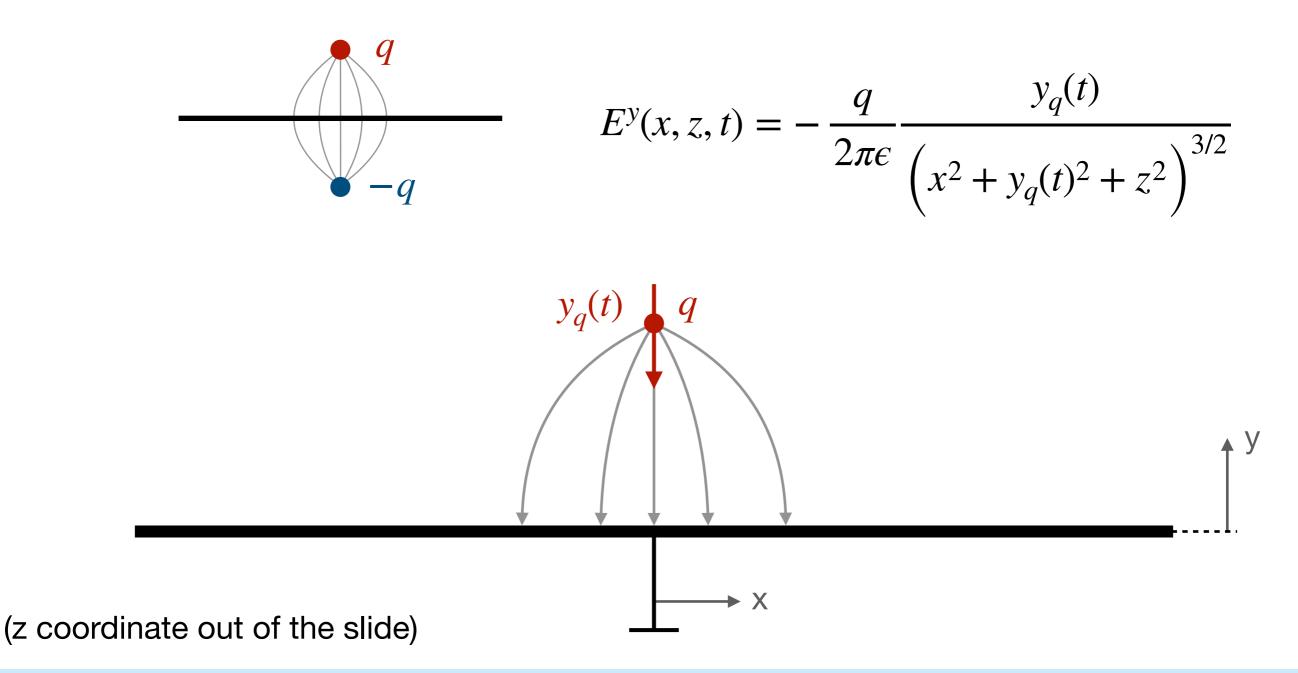
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 - 4.) Total current from electrode: negative change in time of total charge



Electric field produced by charge

Narrow gap between strips: electrode appears as infinite grounded plane

Compute field with method of image charges:

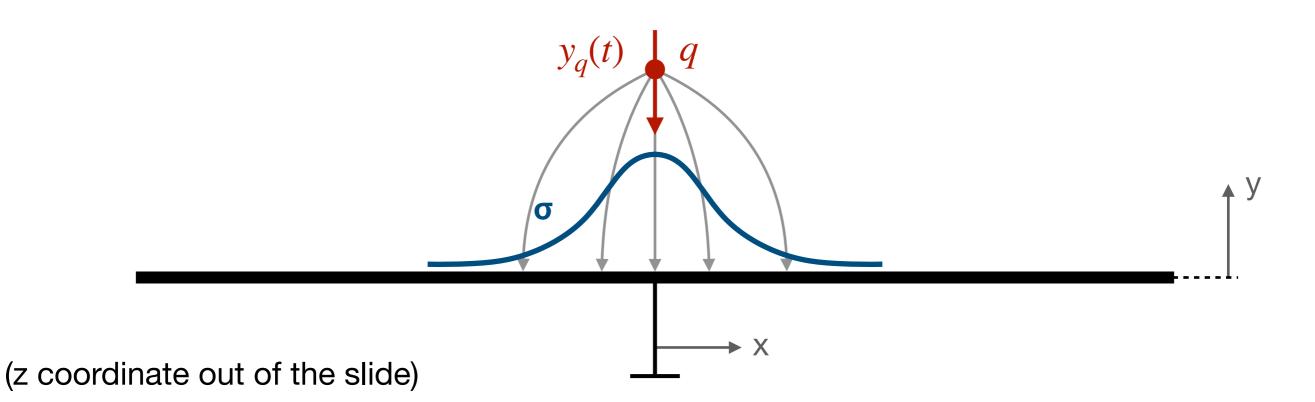


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Surface charge density

$$\sigma = \epsilon \mathbf{E} \cdot \hat{\mathbf{n}} = \epsilon E^{y}$$
Electric field perpendicular to surface

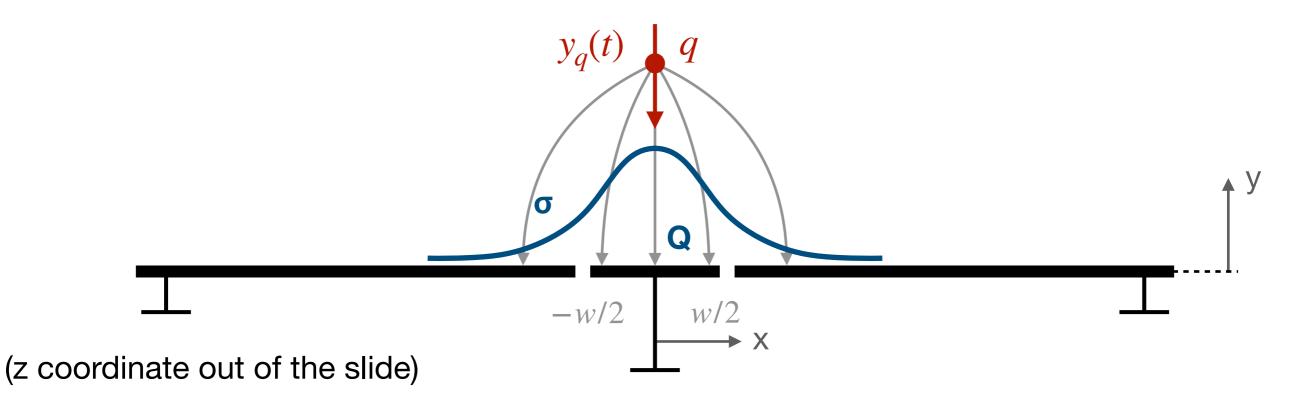
$$\sigma(x, z, t) = -\frac{q}{2\pi} \frac{y_q(t)}{\left(x^2 + y_q(t)^2 + z^2\right)^{3/2}}$$



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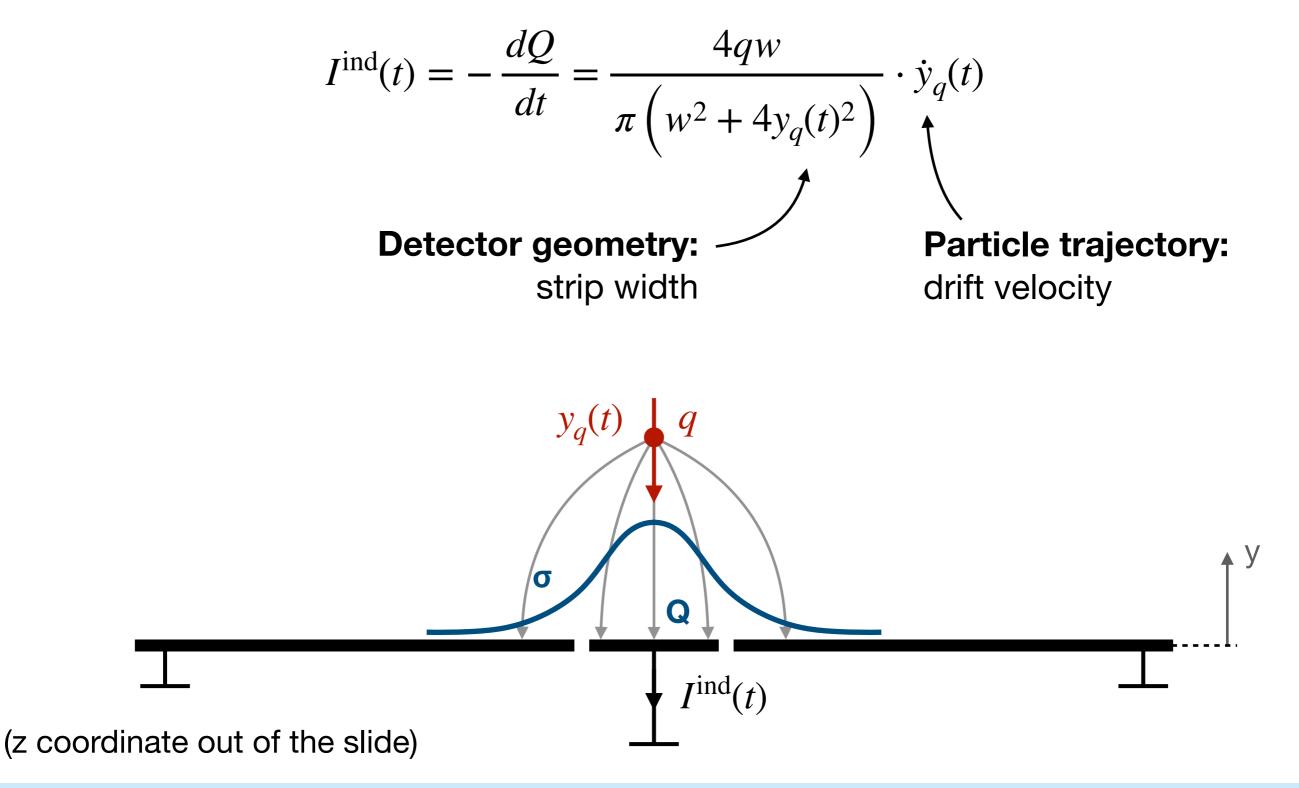
Total charge on strip electrode

$$Q(t) = \int_{-w/2}^{w/2} dx \int_{-\infty}^{\infty} dz \,\sigma(x, z, t) = -2\frac{q}{\pi} \arctan\left(\frac{w}{2y_q(t)}\right)$$



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Total charge on strip electrode



Properties of the signal

Important properties of the induced signal

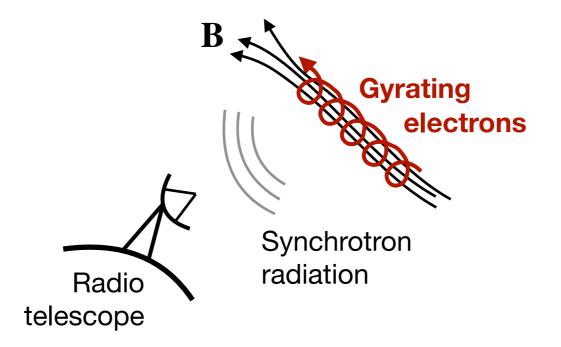
Produced by moving charges

Signal amplitude proportional to number of charges and their velocity

Signal ends when charges reach the electrodes

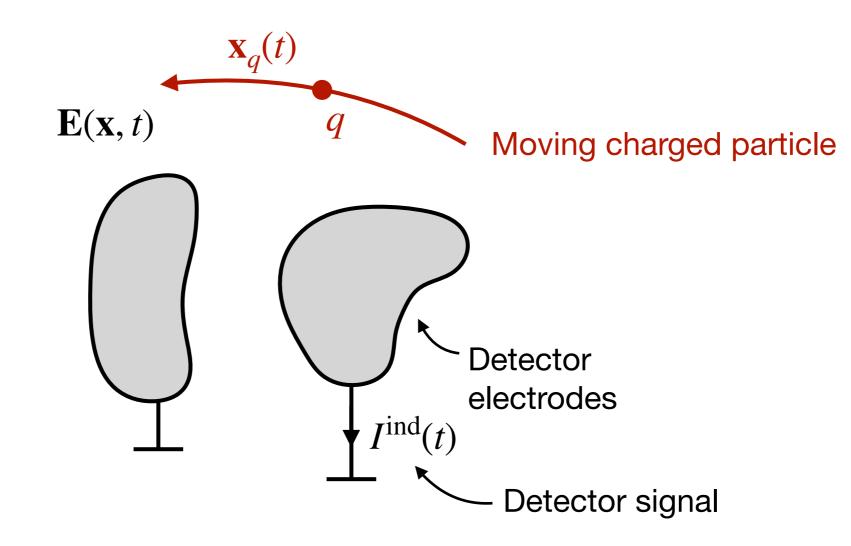
Signal is not due to charge "collection"

Charges can be far away from the electrodes and still induce a signal (radio telescopes!)



This is a "particle-centric" calculation

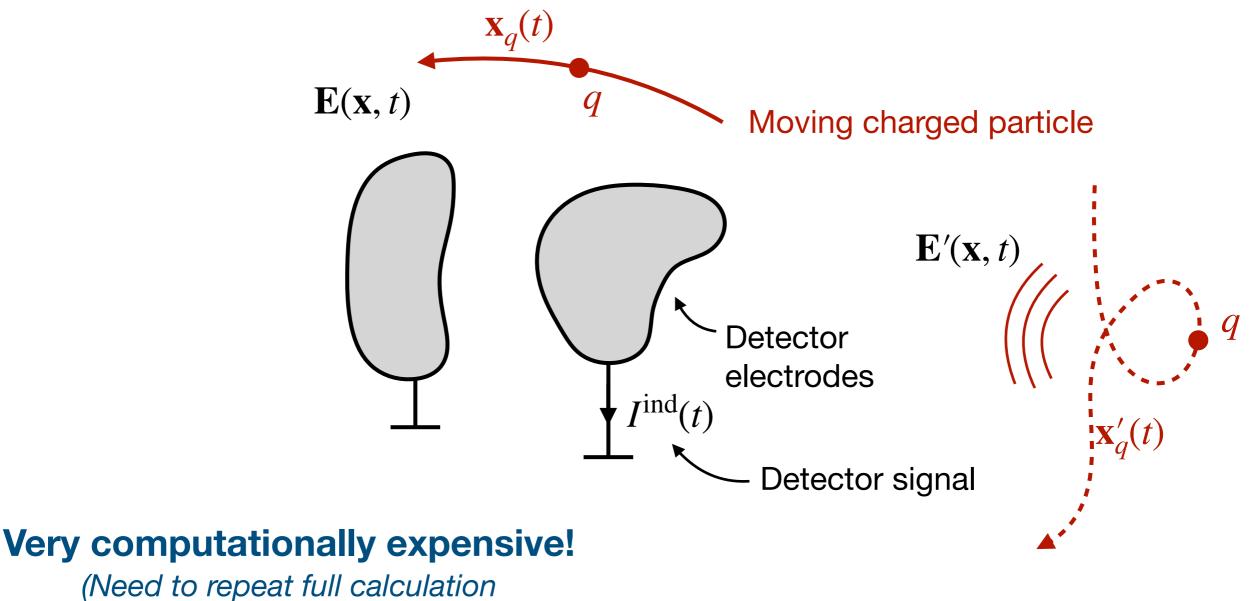
Particle trajectory $\mathbf{x}_q(t) \rightarrow \text{Maxwell's equations} \rightarrow$ electric field distribution $\mathbf{E}(\mathbf{x}, t) \rightarrow \text{induced signal } I^{\text{ind}}(t)$



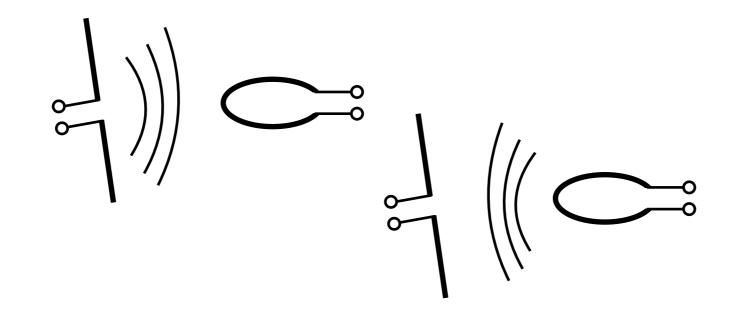
Very computationally expensive!

This is a "particle-centric" calculation

Particle trajectory $\mathbf{x}_q(t) \rightarrow \text{Maxwell's equations} \rightarrow$ electric field distribution $\mathbf{E}(\mathbf{x}, t) \rightarrow \text{induced signal } I^{\text{ind}}(t)$

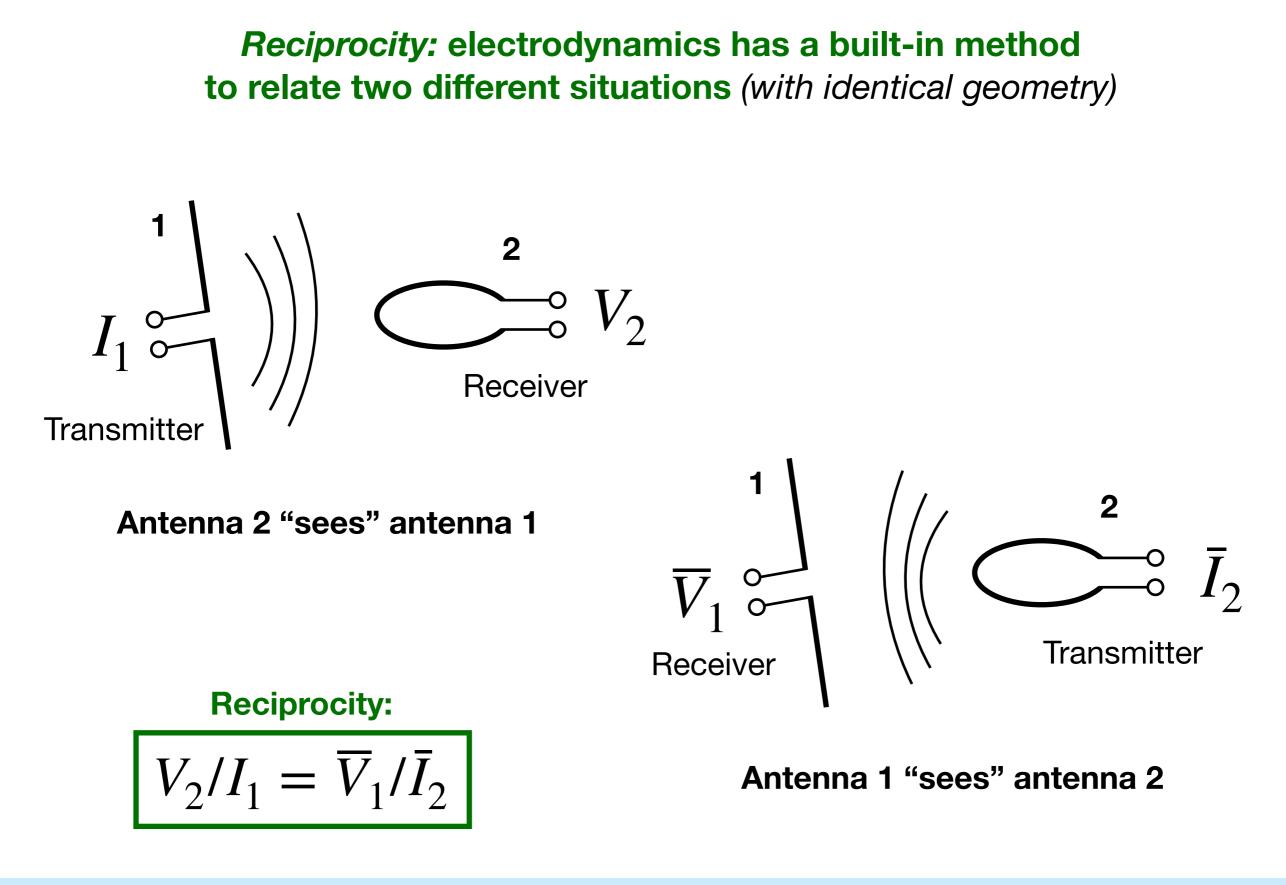


for every trajectory.)

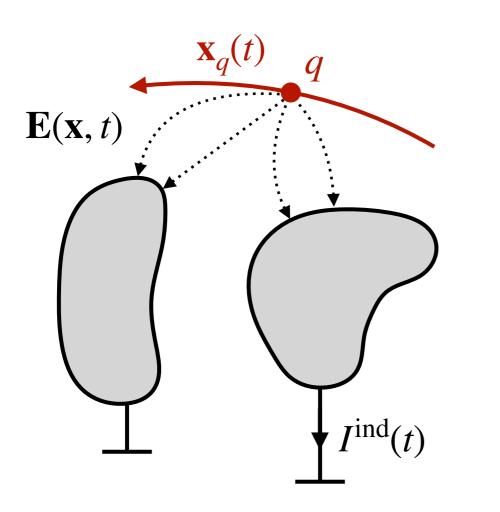


A general and efficient method to compute the signal

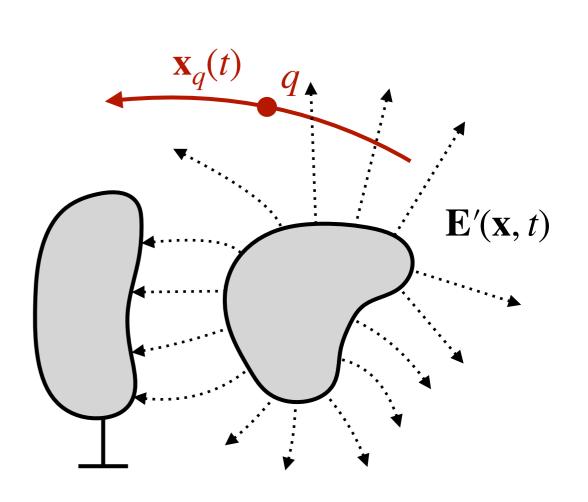
Towards a "detector-centric" calculation



Two views of the same situation





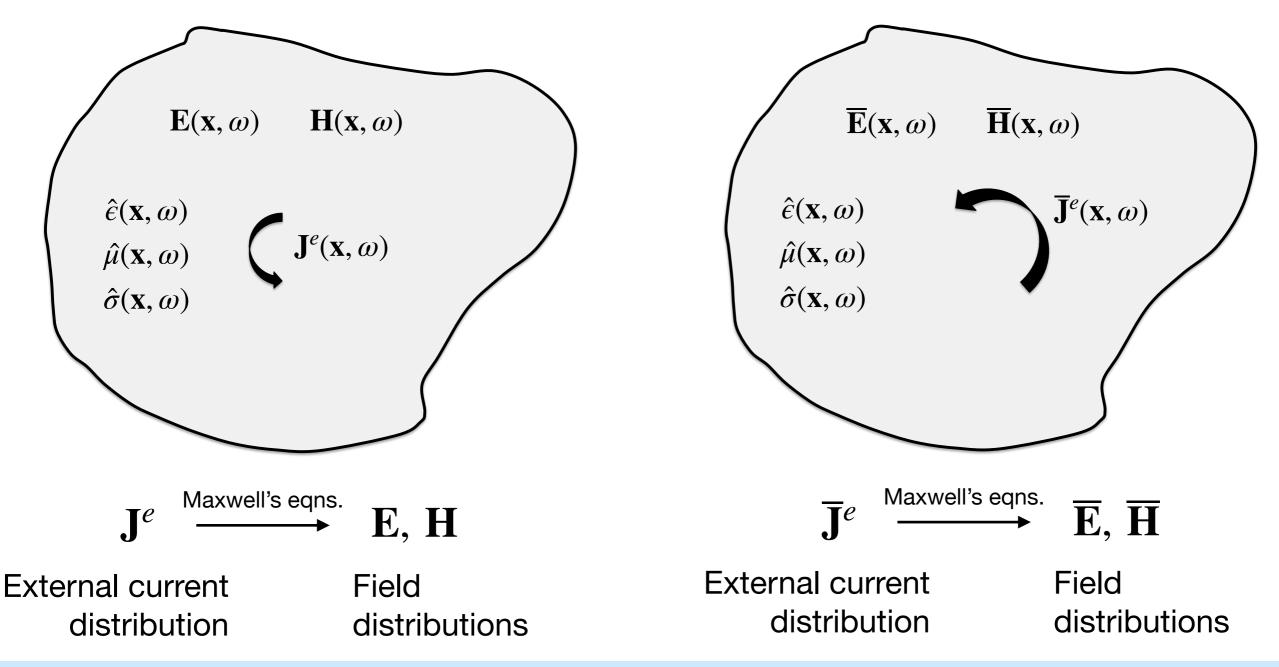


Particle "sees" detector electrode

Towards a "detector-centric" calculation

Reciprocity: electrodynamics has a built-in method to relate two different situations (with identical geometry)

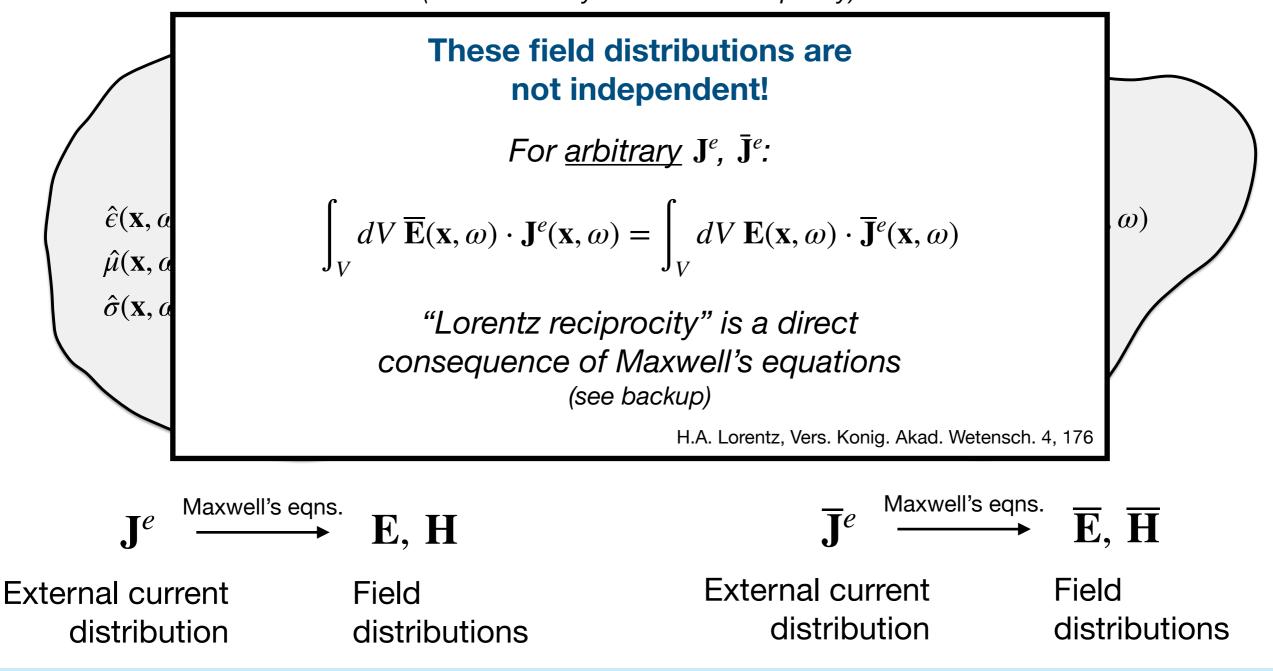
General, linear material distribution: $\epsilon(\mathbf{x})$, $\mu(\mathbf{x})$, $\sigma(\mathbf{x})$ *(taken to be symmetric for simplicity)*



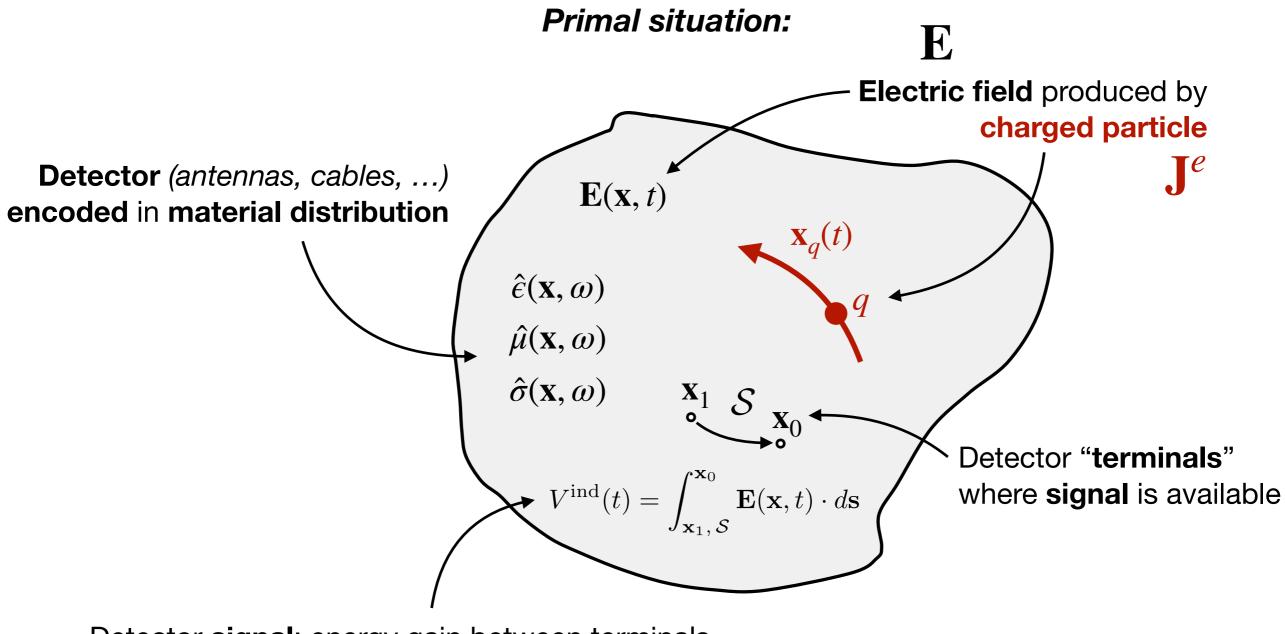
Towards a "detector-centric" calculation

Reciprocity: electrodynamics has a built-in method to relate two different situations (with identical geometry)

General, linear material distribution: $\epsilon(\mathbf{x}), \mu(\mathbf{x}), \sigma(\mathbf{x})$ (taken to be symmetric for simplicity)



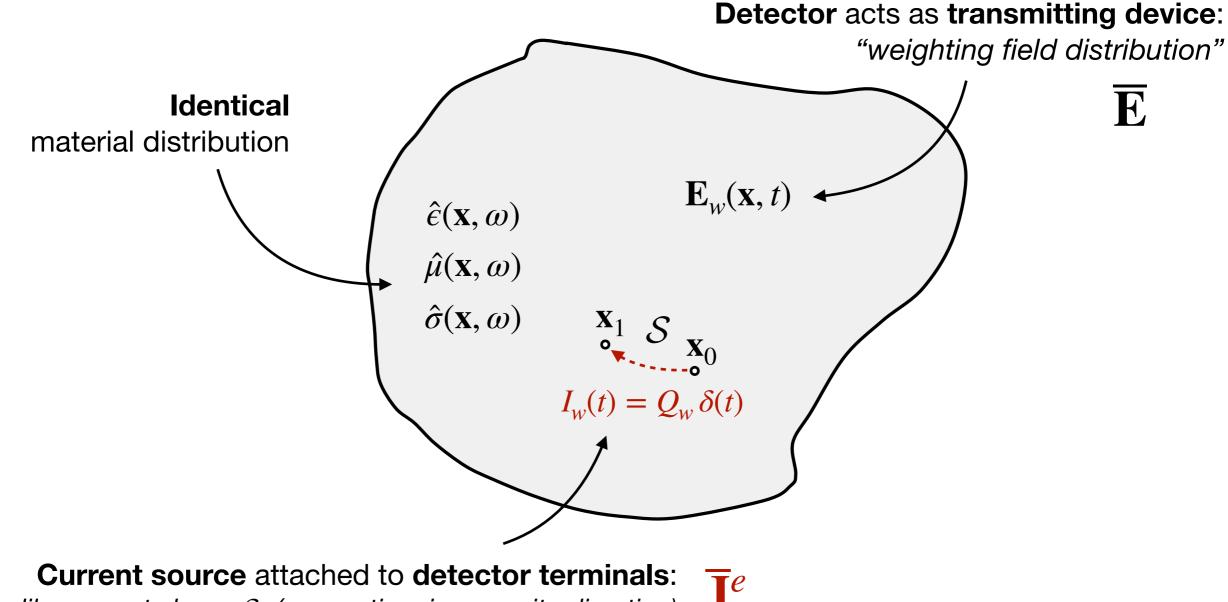
Use reciprocity to compute signal induced in detector



Detector **signal**: energy gain between terminals (measured along a specific path S, $\nabla \times \mathbf{E} \neq 0$ in general!)

Use reciprocity to compute signal induced in detector

The "dual" situation:

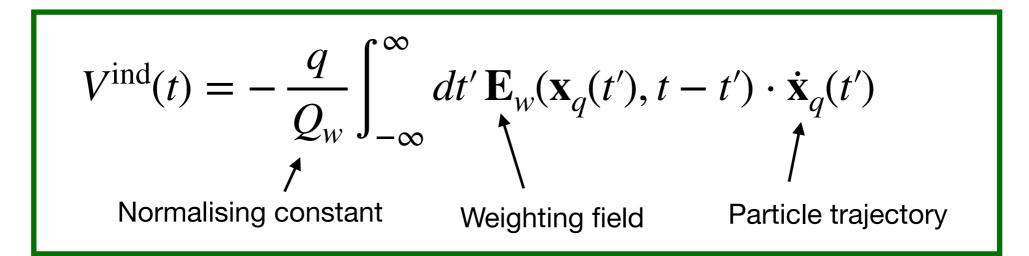


delta-like current along S (convention: in opposite direction)

E $\overline{\mathbf{E}} \equiv \mathbf{E}_{w}$ $\mathbf{X}_q(t)$ $\hat{\epsilon}(\mathbf{x},\omega)$ $\hat{\epsilon}(\mathbf{x},\omega)$ $^{q} \mathbf{J}^{e}$ $\hat{\mu}(\mathbf{x},\omega)$ $\hat{\mu}(\mathbf{x},\omega)$ $\hat{\sigma}(\mathbf{x},\omega) \qquad \underbrace{\mathbf{X}_{1}}_{\mathbf{w}} \underbrace{\mathcal{S}}_{\mathbf{x}_{0}} \mathbf{J}^{\boldsymbol{\theta}}$ $\mathbf{J}^{\boldsymbol{\theta}}$ $I_{w}(t) = Q_{w} \delta(t)$ $\mathbf{x}_1 \ \mathcal{S} \ \mathbf{x}_0$ $\hat{\sigma}(\mathbf{x},\omega)$ Lorentz reciprocity: $\int_{V} dV \mathbf{E}(\mathbf{x}, \omega) \cdot \overline{\mathbf{J}}^{e}(\mathbf{x}, \omega) = \int_{V} dV \overline{\mathbf{E}}(\mathbf{x}, \omega) \cdot \mathbf{J}^{e}(\mathbf{x}, \omega)$ $-Q_{w}V^{\text{ind}}(\omega) = \int_{V} dV \mathbf{E}_{w}(\mathbf{x},\omega) \cdot \mathbf{J}^{e}(\mathbf{x},\omega)$

In the time domain:

"Induced signal = weighting field * particle trajectory"



Weighting field: Green's function for detector signal

Encodes information about detector geometry and environment Reciprocity: compute it by using detector as transmitter (Maxwell solver)

Compute once, use for arbitrary particle trajectories

(Numerical convolution is cheap!)

Fully general, no approximations

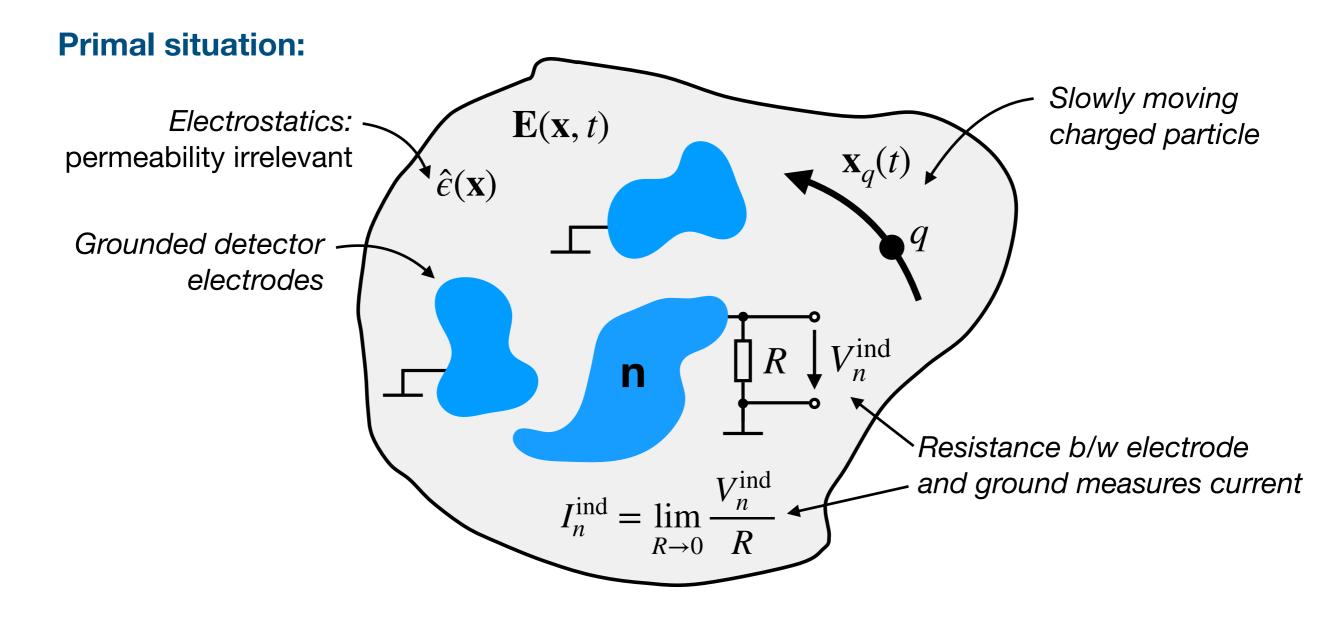
Holds exactly for all linear, anisotropic materials, approximately for nonlinear, anisotropic materials

Nonrelativistic limit

Charges move nonrelativistically in a typical detector (gas, silicon)

Quasi-electrostatics ($c \rightarrow \infty$): no radiation, no propagation effects, ...

Also: want the induced <u>current</u> (on a grounded electrode)

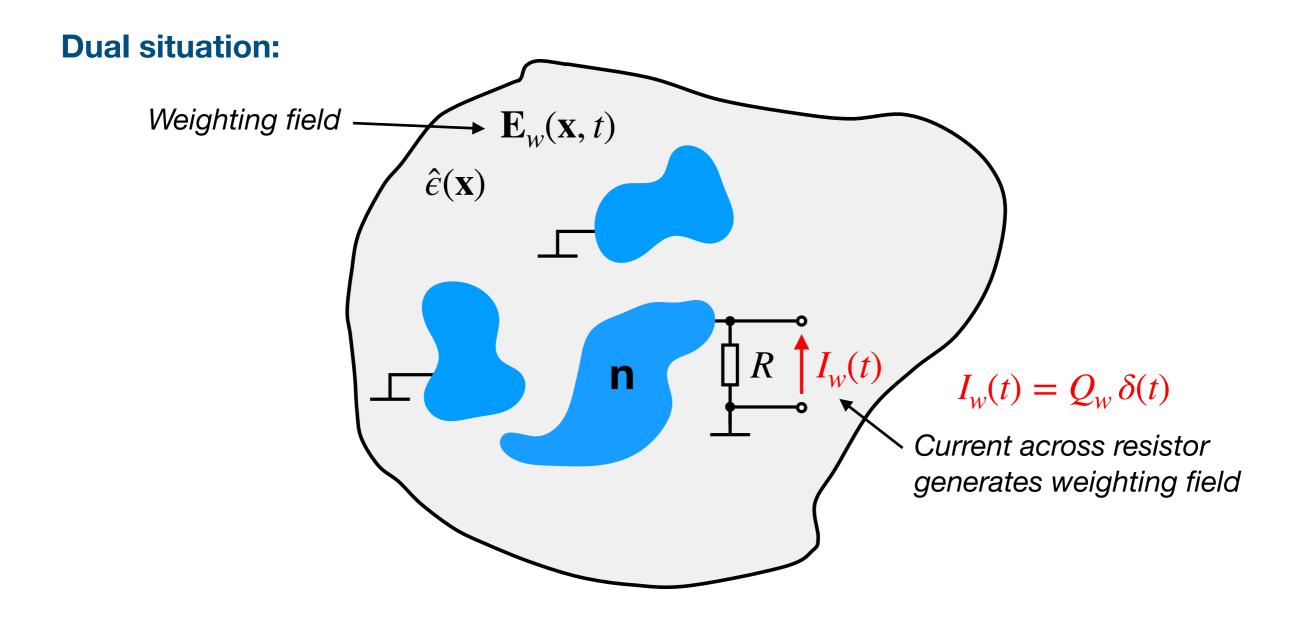


Nonrelativistic limit

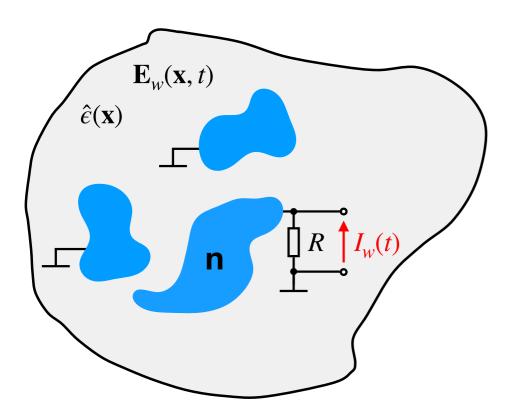
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Quasi-electrostatics ($c \rightarrow \infty$): no radiation, no propagation effects, ...

Also: want the induced <u>current</u> (on a grounded electrode)



Weighting field



1.) The current I_w places a charge Q_w on electrode n at t = 0

 $I_w(t) = Q_w \,\delta(t)$

- **2.)** This puts the electrode at potential V(0) and generates the electric field $\mathbf{E}_{w}(\mathbf{x}, t)$
- 3.) The electrode discharges through the resistor *R* for t > 0
 → time-dependent potential V(t)

Quasi-electrostatic limit: evolution is sequence of electrostatic configurations

If the field is $E_n(x; V)$ for electrode *n* at potential V, the weighting field is

$$\mathbf{E}_{w}(\mathbf{x},t) = \mathbf{E}_{n}(\mathbf{x};V(t)) = \frac{V(t)}{V_{w}} \mathbf{E}_{n}(\mathbf{x};V_{w})$$
 Arbitrary constant

(Field scales homogeneously with the potential)

Induced voltage

Weighting field:

$$\mathbf{E}_{w}(\mathbf{x},t) = \frac{V(t)}{V_{w}} \mathbf{E}_{n}(\mathbf{x};V_{w})$$

Signal theorem:

$$V^{\text{ind}}(t) = -\frac{q}{Q_w} \int_{-\infty}^{\infty} dt' \mathbf{E}_w(\mathbf{x}_q(t'), t - t') \cdot \dot{\mathbf{x}}_q(t')$$

Induced current:

$$I^{\text{ind}}(t) = \lim_{R \to 0} \frac{V^{\text{ind}}(t)}{R}$$

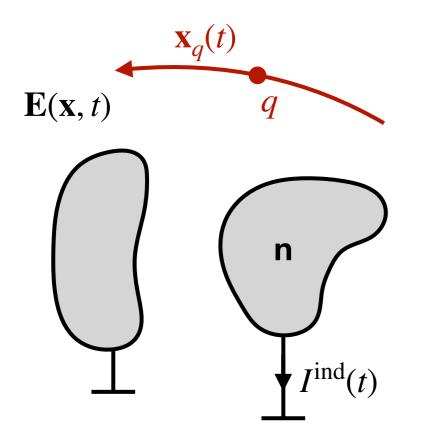
$$\implies I^{\text{ind}}(t) = \lim_{R \to 0} -\frac{q}{Q_w R} \int dt' \frac{V_n(t-t')}{V_w} \mathbf{E}_n(\mathbf{x}_q(t'); V_w) \cdot \dot{\mathbf{x}}_q(t')$$

The discharge is very fast for small resistances

$$\lim_{R \to 0} \frac{V_n(t)}{R} = Q_w \,\delta(t)$$

$$\implies I^{\text{ind}}(t) = -\frac{q}{V_w} \mathbf{E}_n(\mathbf{x}_q(t); V_w) \cdot \dot{\mathbf{x}}_q(t)$$

Induced voltage



"Detector-centric" expression for current induced on grounded readout electrodes:

(Nonrelativistic limit)

$$I^{\text{ind}}(t) = -\frac{q}{V_w} \mathbf{E}_n(\mathbf{x}_q(t); V_w) \cdot \dot{\mathbf{x}}_q(t)$$

"Ramo-Shockley theorem"

Proceedings of the I.R.E. September, 1939 Currents Induced by Electron Motion*

SIMON RAMO[†], ASSOCIATE MEMBER, I.R.E.

Summary—A method is given for computing the instantaneous current induced in neighboring conductors by a given specified motion of electrons. The method is based on the repeated use of a simple equation giving the current due to a single electron's movement and is believed to be simpler than methods previously described. The methods

... specifically for the quasi-static case

Currents to Conductors Induced by a Moving Point Charge

Derived in the 1930s by

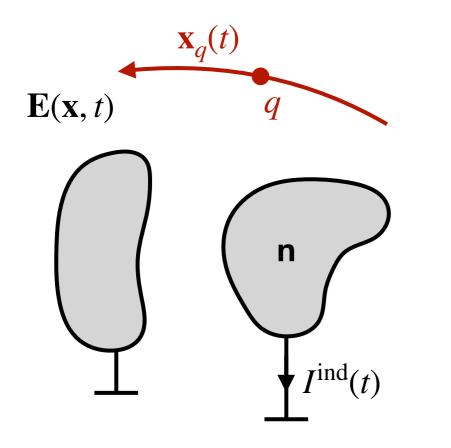
Ramo and Shockley ...

W. SHOCKLEY Bell Telephone Laboratories, Inc., New York, N. Y. (Received May 14, 1938)

General expressions are derived for the currents which flow in the external circuit connecting a system of conductors when a point charge is moving among the conductors. The results are applied to obtain explicit expressions for several cases of practical interest.

584

Induced voltage



"Detector-centric" expression for current induced on grounded readout electrodes:

(Nonrelativistic limit)

$$I^{\text{ind}}(t) = -\frac{q}{V_w} \mathbf{E}_n(\mathbf{x}_q(t); V_w) \cdot \dot{\mathbf{x}}_q(t)$$

"Ramo-Shockley theorem"

Weighting field

Encodes detector geometry, can be computed once and for all

Particle trajectory

Nonzero <u>velocity</u> is required to produce a nonzero signal

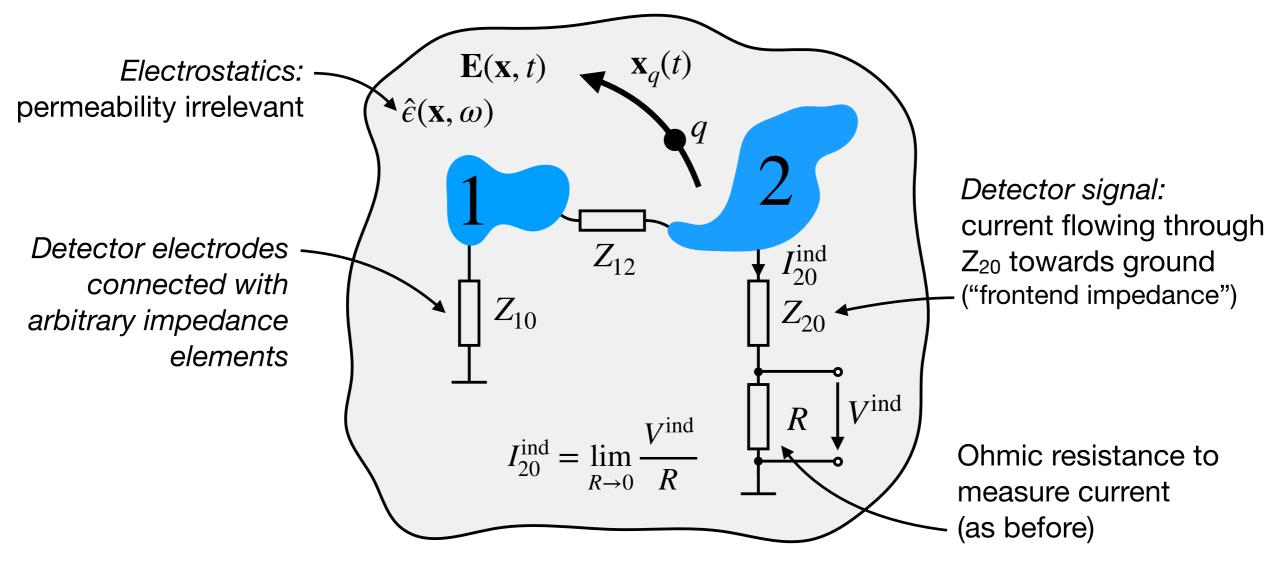
Very efficient! Multiplication instead of Poisson equation ...

Grounded electrodes?

Real detector electrodes are embedded in electrical circuits

Insulation resistance, frontend electronics ...

Primal situation:

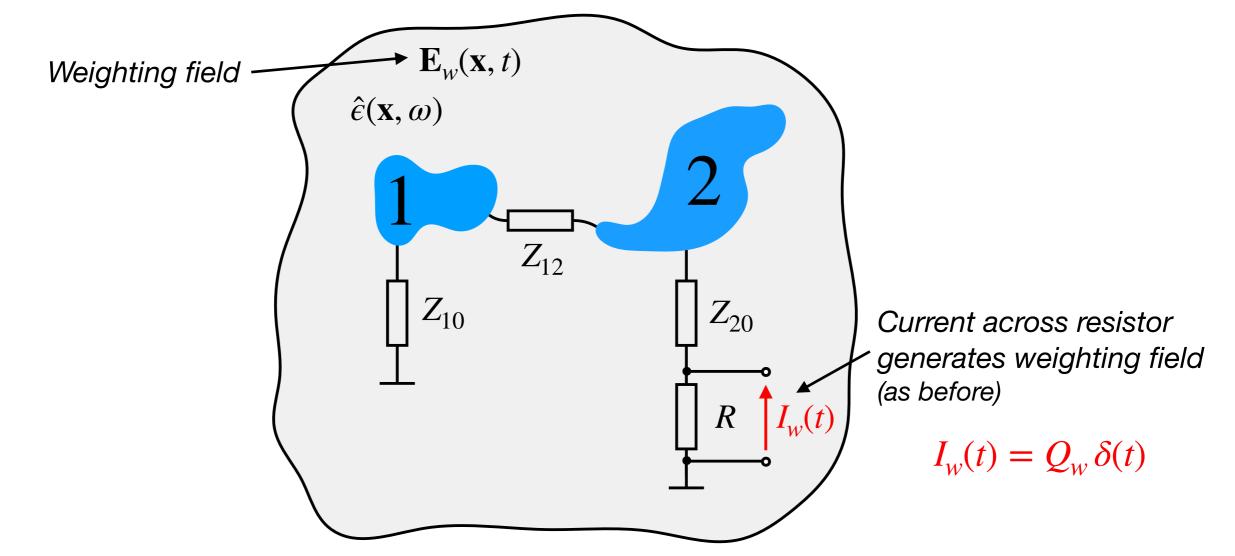


Grounded electrodes?

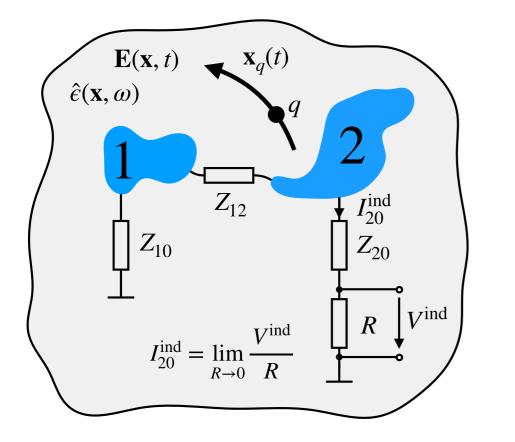
Real detector electrodes are embedded in electrical circuits

Insulation resistance, frontend electronics ...

Dual situation:



Induced signal



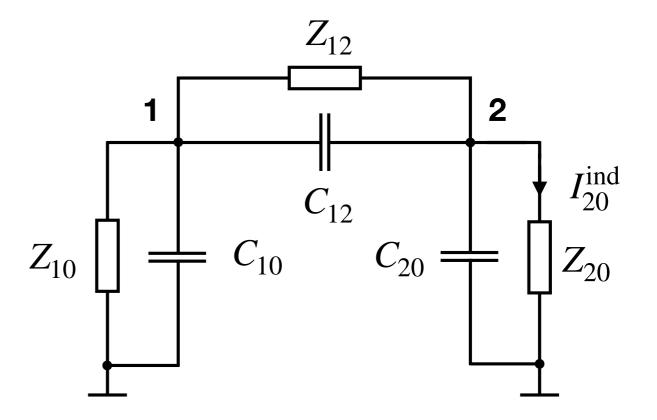
Derivation works as before:

$$\mathbf{E}_{w}(\mathbf{x},t) = \frac{V_{2}(t)}{V_{w}} \mathbf{E}_{2}(\mathbf{x};V_{w})$$

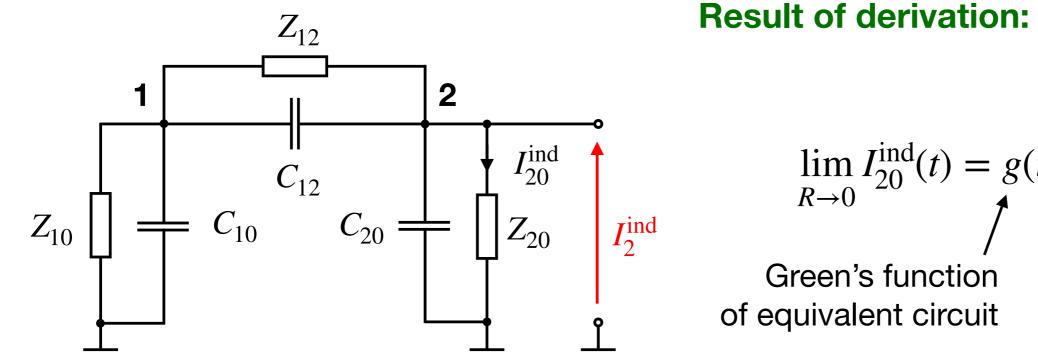
Evolution of V₂(t) now depends on the equivalent circuit of the situation

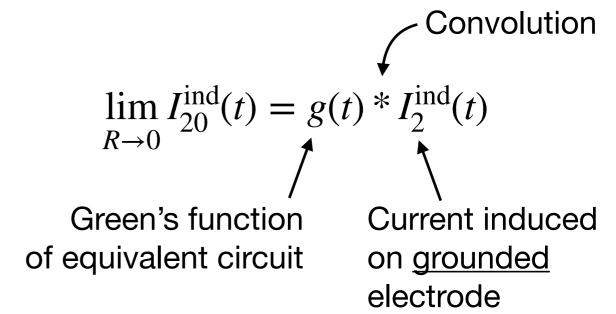
Equivalent circuit:

Explicit representation of circuit including mutual capacitances between electrodes



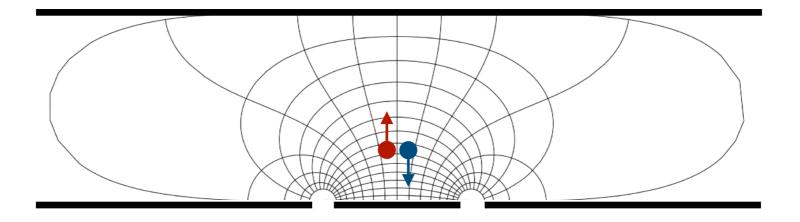
Induced signal





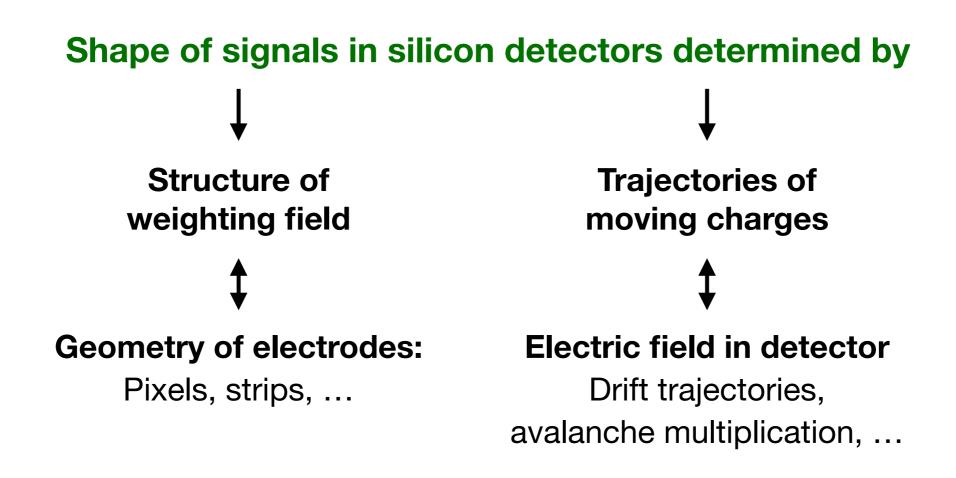
Practical workflow:

- 1.) Compute current $I_2^{ind}(t)$ induced on grounded electrode with Ramo-Shockley theorem
- 2.) Place this current as a source into equivalent circuit and solve with SPICE (or other simulator), read off $I_{20}^{ind}(t)$



Signals in silicon detectors

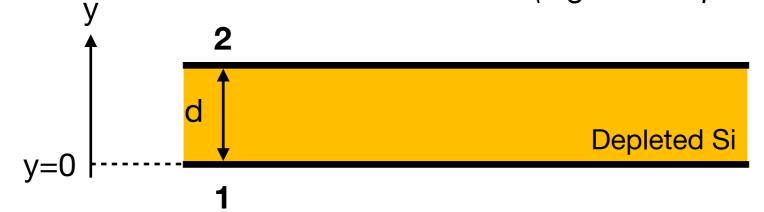
Signals in silicon detectors



In the following: discuss some common situations

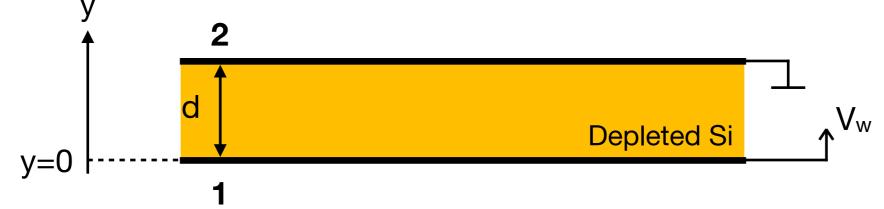
Parallel-plate geometry

(e.g. silicon pixel detector with large pitch)



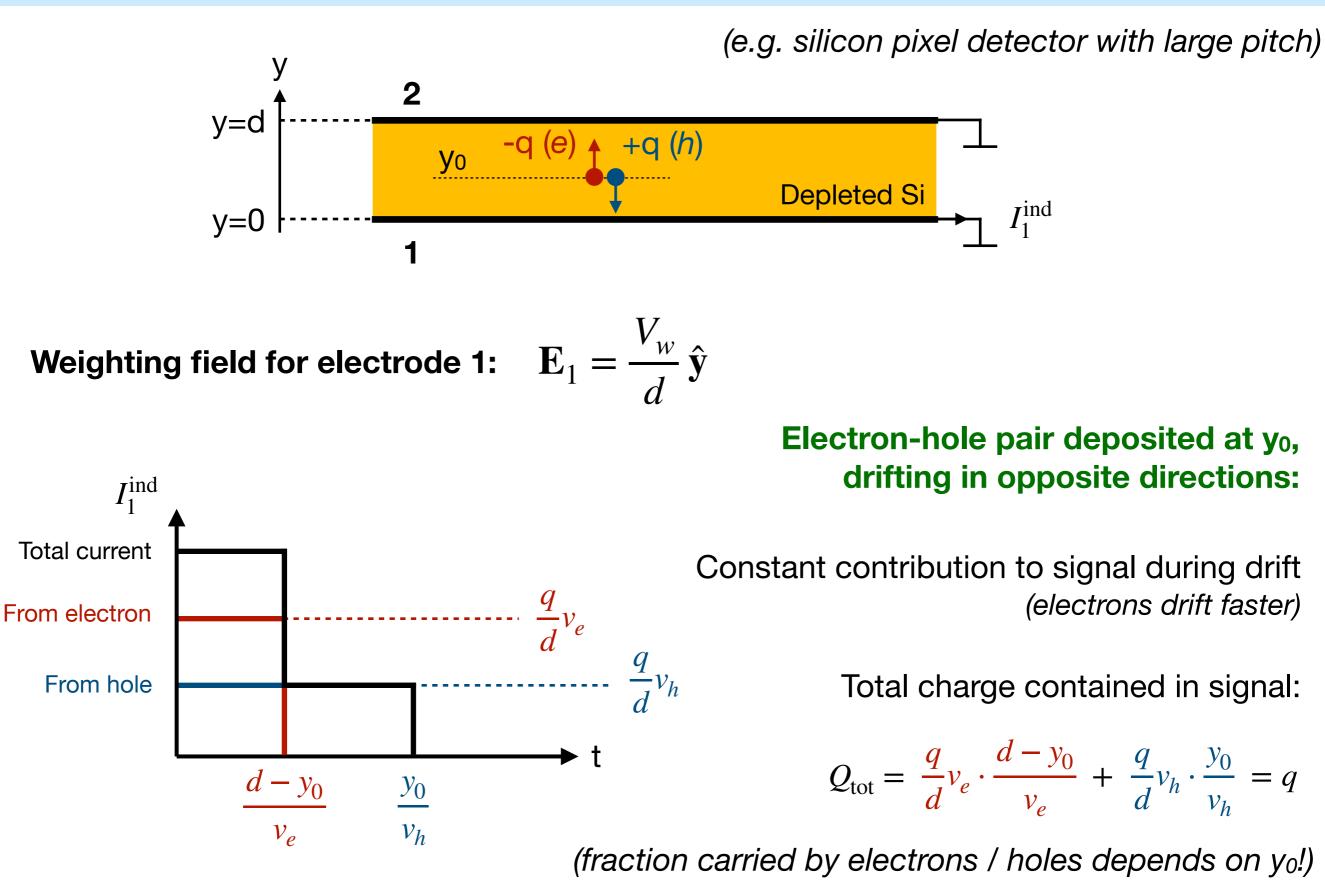
Parallel-plate geometry

(e.g. silicon pixel detector with large pitch)



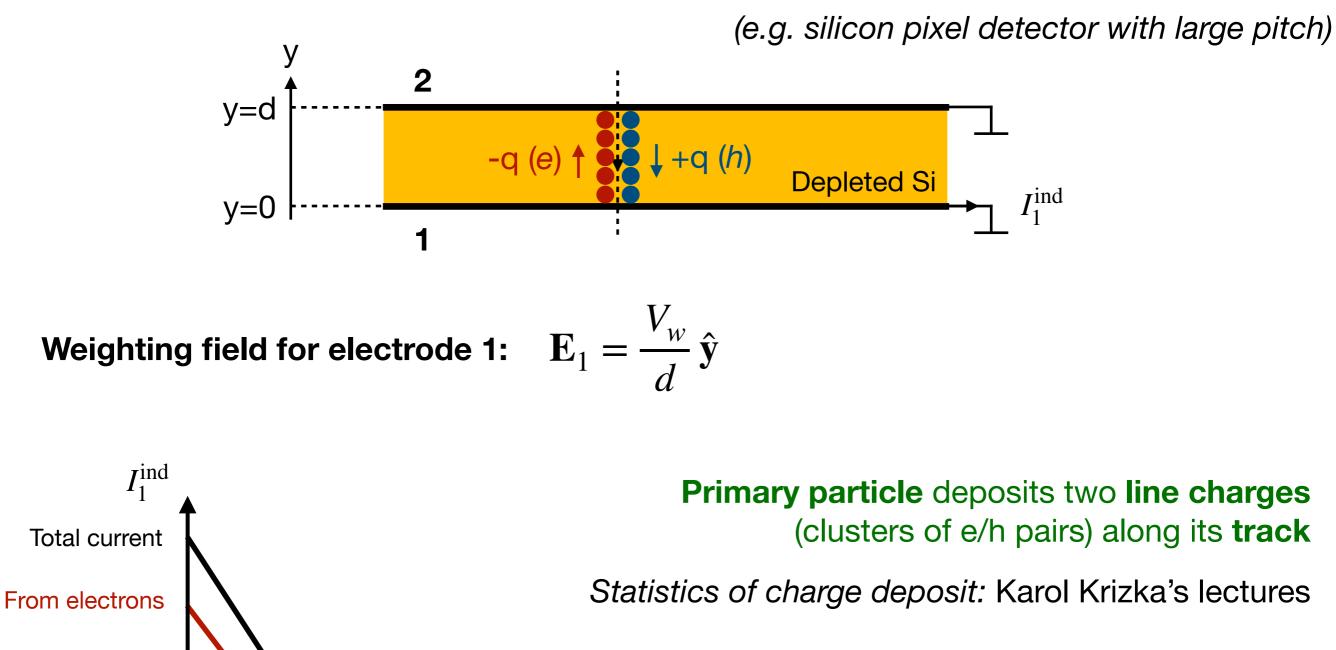
Weighting field for electrode 1: $\mathbf{E}_1 = \frac{V_w}{d} \hat{\mathbf{y}}$

Signal induced by electron-hole pair



Signal induced by charged particle

t



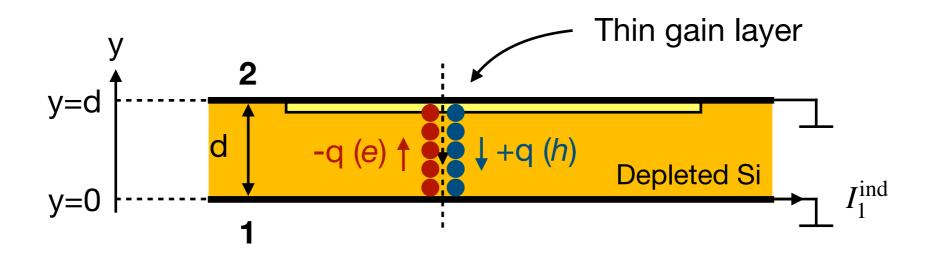
Number of drifting charges reduces linearly over time → triangular signal

From holes

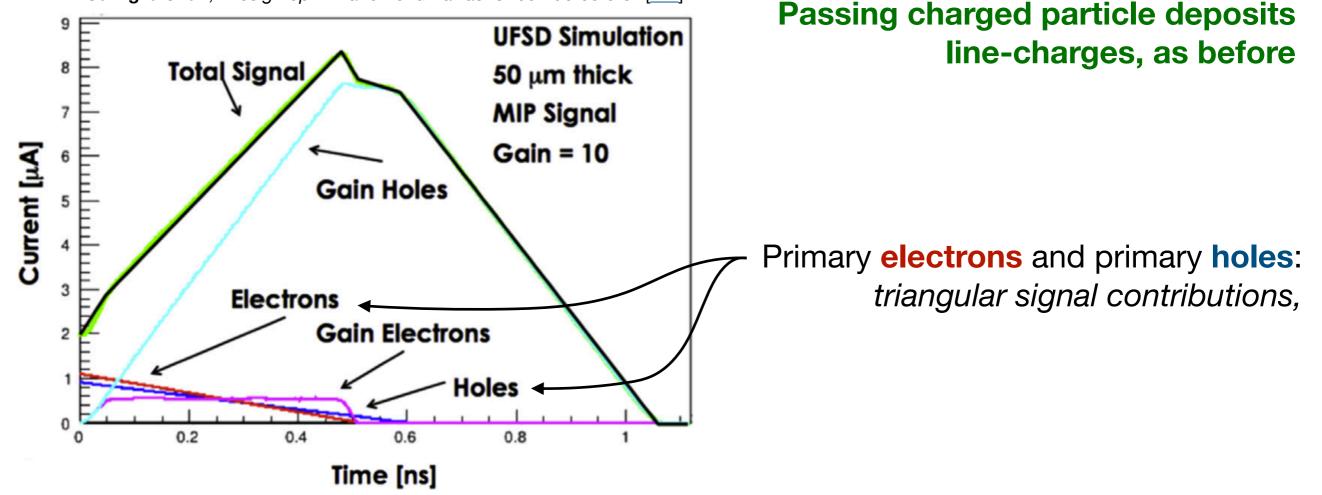
 v_e

Vh

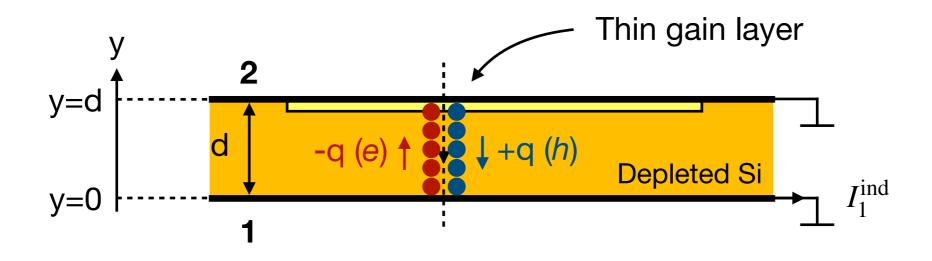
Signals in LGADs



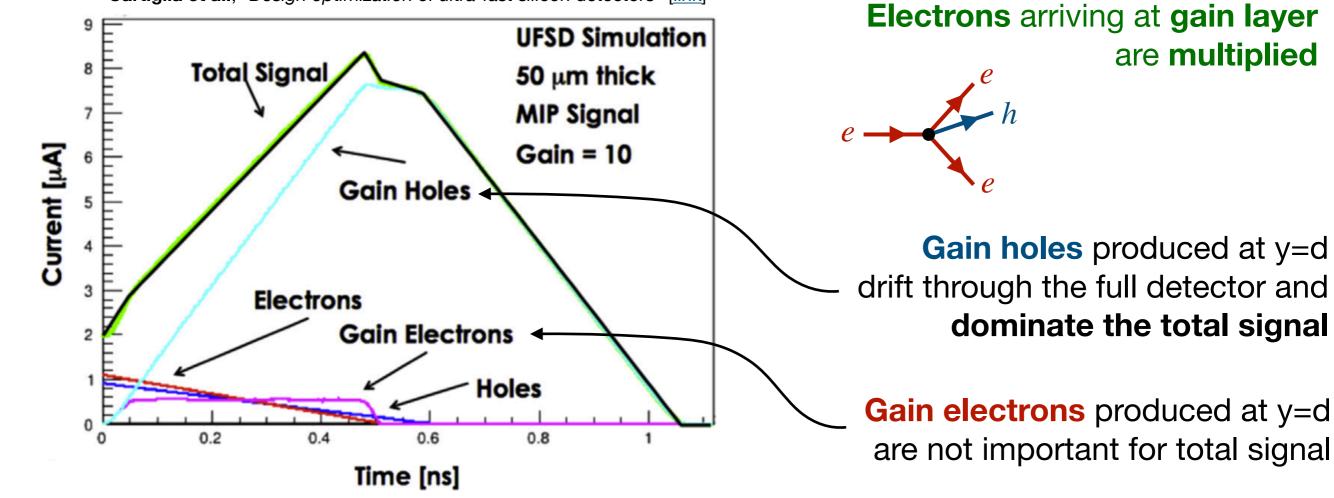
Cartiglia et al., "Design optimization of ultra-fast silicon detectors" [link]



Signals in LGADs



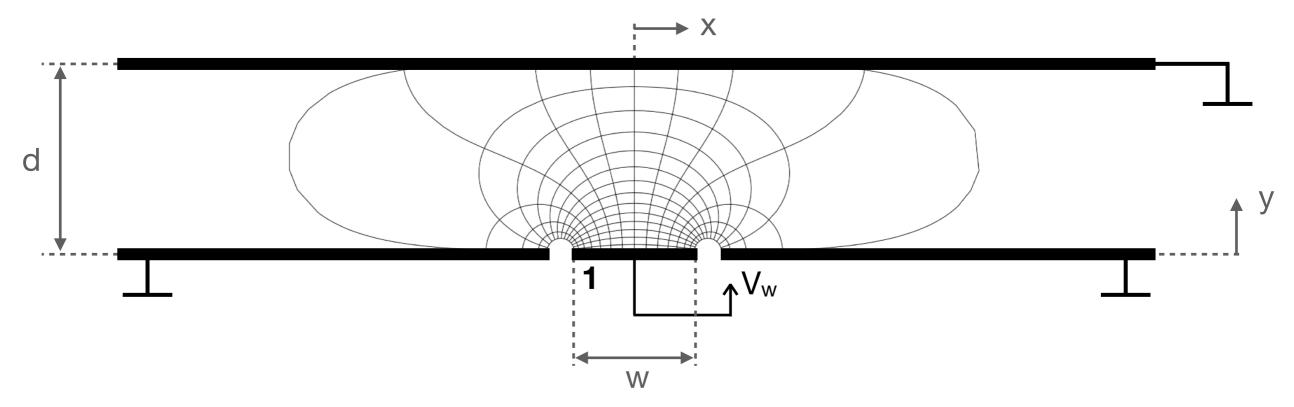
Cartiglia et al., "Design optimization of ultra-fast silicon detectors" [link]



The real world is not a parallel plate capacitor!

Realistic detector geometries have more complicated weighting fields ...

 \rightarrow revisit the strip geometry from earlier



Weighting field for electrode 1:

$$E_1^y = \frac{V_w}{2d} \left[\frac{\sinh\left(\pi \frac{x + w/2}{d}\right)}{\cosh\left(\frac{x + w/2}{d}\right) - \cos\left(\frac{\pi y}{d}\right)} - \frac{\sinh\left(\pi \frac{x - w/2}{d}\right)}{\cosh\left(\frac{x - w/2}{d}\right) - \cos\left(\frac{\pi y}{d}\right)} \right]$$

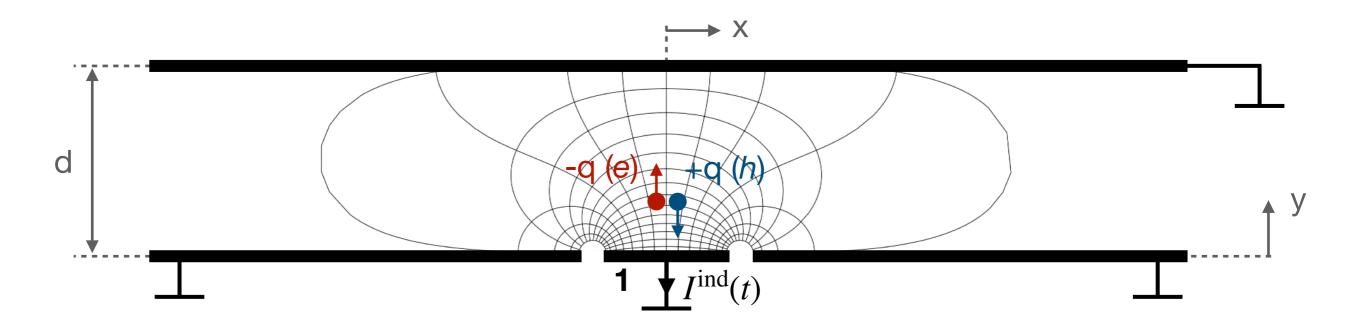
Heubrandtner et al., "Static Electric Fields in an Infinite Plane Condensor with One or Three Homogeneous Layers" [link]

Philipp Windischhofer

The real world is not a parallel plate capacitor!

Realistic detector geometries have more complicated weighting fields ...

 \rightarrow revisit the strip geometry from earlier



For $\mathbf{w} \gg \mathbf{d}$, the situation reverts to the parallel-plate geometry

For $\mathbf{w} \sim \mathbf{d}$, the weighting field increases towards the strip

 \rightarrow signal dominated by moving charges <u>close</u> to the strip

... similar for weighting field for pixel geometry

Heubrandtner et al., "Static Electric Fields in an Infinite Plane Condensor with One or Three Homogeneous Layers" [link]

Summary

Electrical signals in detectors are <u>exclusively</u> due to induction by moving charged particles

Signals in silicon detectors may be computed with the Ramo-Shockley theorem (itself a special case of a more general fact)

$$I^{\text{ind}}(t) = -\frac{q}{V_w} \mathbf{E}_n(\mathbf{x}_q(t); V_w) \cdot \dot{\mathbf{x}}_q(t)$$

Weighting field of electrode Particle trajectory

Depending on the **geometry** and the **charge trajectory**, either electrons or holes are responsible for the **dominant part of the signal**

Any questions? Feel free to contact me at *philipp.windischhofer@cern.ch*

W. Shockley, *Currents to Conductors Induced by a Moving Point Charge*, Journal of Applied Physics. 9 (10): 635 (1938)

S. Ramo, Currents induced in electron motion, PROC. IRE 27, 584 (1939)

W. Riegler, P. Windischhofer, *Signals induced on electrodes by moving charges: a general theorem for Maxwell's equations based on Lorentz-reciprocity,* Nucl. Instrum. Meth. A 980, 164471 (2020)

W. Riegler, *Signals in particle detectors*, CERN Academic Training Lectures, <u>https://indico.cern.ch/event/843083/</u>

Backup

Maxwell's equations and Lorentz reciprocity

We assume the most general form of Maxwell's equation anisotropic material of position- and frequency-dependent matrix $\hat{\epsilon}(\mathbf{x}, \omega)$, permeability matrix $\hat{\mu}(\mathbf{x}, \omega)$ and con- $\hat{\sigma}(\mathbf{x}, \omega)$. These 3 × 3 matrices relate the vector fields $\mathbf{D} = \hat{\epsilon} \mathbf{E} \qquad \mathbf{B} = \hat{\mu} \mathbf{H} \qquad \mathbf{J} = \hat{\sigma} \mathbf{E}$ The source of the fields is an externally improved	ndent permittivity nductivity matrix (1)		
The source of the fields is an externally impressed $\mathbf{J}^{e}(\mathbf{x}, \omega)$. In the Fourier domain, Maxwell's equations	· ·		
$\nabla \cdot \hat{\varepsilon} \mathbf{E} = \rho \qquad \nabla \cdot \hat{\mu} \mathbf{H} = 0$	$\nabla \cdot (\mathbf{F} \times \mathbf{G}) = \mathbf{G} \cdot (\nabla \times \mathbf{F}) - \mathbf{F} \cdot (\nabla \times \mathbf{G})$	(4)	
$\nabla \times \mathbf{E} = -i\omega\hat{\mu}\mathbf{H} \qquad \nabla \times \mathbf{H} = \mathbf{J}^e + \hat{\sigma}\mathbf{E} + i\omega\hat{\varepsilon}\mathbf{E}$	We can therefore write		
	$\nabla \cdot (\mathbf{E} \times \overline{\mathbf{H}}) = \overline{\mathbf{H}} (\nabla \times \mathbf{E}) - \mathbf{E} (\nabla \times \overline{\mathbf{H}})$ $= -\mathbf{E} \overline{\mathbf{J}}^e - i\omega \overline{\mathbf{H}} \hat{\mu} \mathbf{H} - \mathbf{E} (\hat{\sigma}^T + i\omega \hat{\varepsilon}^T) \overline{\mathbf{E}}$	(5)	
	$= -\mathbf{E}\overline{\mathbf{J}}^{e} - i\omega\overline{\mathbf{H}}\hat{\mu}\mathbf{H} - \mathbf{E}(\hat{\sigma}^{T} + i\omega\hat{\varepsilon}^{T})\overline{\mathbf{E}}$	(6)	
	$\nabla \cdot (\overline{\mathbf{E}} \times \mathbf{H}) = \mathbf{H} (\nabla \times \overline{\mathbf{E}}) - \overline{\mathbf{E}} (\nabla \times \mathbf{H})$ $= -\overline{\mathbf{E}} \mathbf{J}^{e} - i\omega \mathbf{H} \hat{\mu}^{T} \overline{\mathbf{H}} - \overline{\mathbf{E}} (\hat{\sigma} + i\omega \hat{\varepsilon}) \mathbf{E}$	(7)	
	$= -\overline{\mathbf{E}}\mathbf{J}^{e} - i\omega\mathbf{H}\hat{\mu}^{T}\overline{\mathbf{H}} - \overline{\mathbf{E}}(\hat{\sigma} + i\omega\hat{\varepsilon})\mathbf{E}$	(8)	
	By subtracting the two expressions and using the relation $\mathbf{G}\hat{m}\mathbf{F} = \mathbf{F}\hat{n}$ we get		
	$\nabla (\mathbf{E} \times \overline{\mathbf{H}} - \overline{\mathbf{E}} \times \mathbf{H}) = \overline{\mathbf{E}} \mathbf{J}^e - \mathbf{E} \overline{\mathbf{J}}^e$	(9)	
	Integrating over a volume <i>V</i> enclosed by surface <i>A</i> and theorem we have	ver a volume V enclosed by surface A and applying Gauss' have	
	$\oint_{A} (\mathbf{E} \times \overline{\mathbf{H}} - \overline{\mathbf{E}} \times \mathbf{H}) d\mathbf{A} = \int_{V} (\overline{\mathbf{E}} \mathbf{J}^{e} - \mathbf{E} \overline{\mathbf{J}}^{e}) dV$	(10)	

Drift velocities in silicon

